

isc N-Channel MOSFET Transistor

FTP03N03N

• FEATURES

- Static drain-source on-resistance:
 $R_{DS(on)} \leq 3m\Omega$
- Enhancement mode
- Fast Switching Speed
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• DESCRIPTION

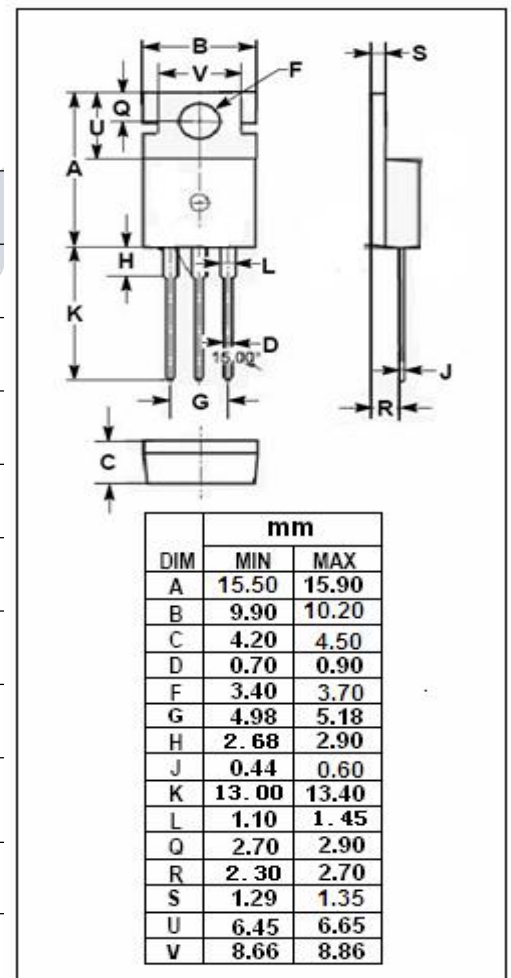
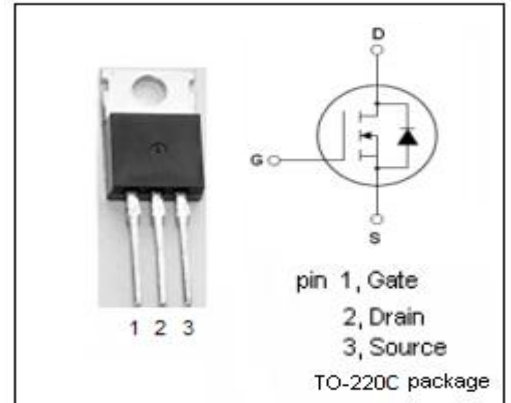
- Be suitable for synchronous rectification for server and general purpose applications

• ABSOLUTE MAXIMUM RATINGS(T_a=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	30	V
V _{GS}	Gate-Source Voltage	±20	V
I _D	Drain Current-Continuous	150	A
I _{DM}	Drain Current-Single Pulsed	600	A
P _D	Total Dissipation @T _c =25°C	100	W
T _j	Max. Operating Junction Temperature	150	°C
T _{stg}	Storage Temperature	-55~150	°C

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th(ch-c)}	Channel-to-case thermal resistance	1.25	°C/W



isc N-Channel MOSFET Transistor**FTP03N03N****ELECTRICAL CHARACTERISTICS** $T_C=25^{\circ}\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0V; I_D=250\ \mu\text{A}$	30			V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}; I_D=250\ \mu\text{A}$	1		3	V
$R_{DS(on)}$	Drain-Source On-Resistance	$V_{GS}=10V; I_D=75A$			3	$\text{m}\Omega$
I_{GSS}	Gate-Source Leakage Current	$V_{GS}=\pm 20V; V_{DS}=0V$			± 100	nA
I_{DSS}	Drain-Source Leakage Current	$V_{DS}=30V; V_{GS}=0V$			1	μA
V_{SD}	Diode forward voltage	$I_S=50A; V_{GS}=0V$			1.2	V

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